Interplay between structural changes, surface states and quantum confinement effects in thin films of semiconducting Mg₂Si and Ca₂Si

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Supplementary materials



Fig. S1 Changes in the in-plane lattice parameters and interlayer distances (d_L) of cubic Me₂Si(111) thin films. The corresponding film structures are also shown. $d_{L,1}$, $d_{L,2}$, ..., $d_{L,inside}$ indicate surface, subsurface, ..., middle or bulk-like layers, respectively. One bulk unit cell is indicated by a red rectangle.



Fig. S2 Changes in the in-plane lattice parameters and interlayer distances (d_L) of orthorhombic Ca₂Si(111) thin films. The corresponding film structures are also shown. $d_{L,1}$, $d_{L,2}$, ..., $d_{L,inside}$ indicate surface, subsurface, ..., middle or bulk-like layers, respectively. One bulk unit cell is indicated by a red rectangle.

Atom name	r relative units	v relative units	7 Å				
	Cubic Mg ₂ Si(111) $d =$	$= 0.5 \text{ nm} \ a_1 = 4.458 \text{ Å}$	<i>4.9 1</i> 1				
Μα	0.0000	0.0000	0.000				
Si	0.0000	0.3333	0.679				
Ma	0.3333	0.5555	1.704				
Mg	0.5555	0.3333	2 172				
si	0.0007	0.5555	3.473 A A07				
Ma	0.5555	0.0007	5 176				
Orthorho							
Μσ	0 4894	0 2500	0.000				
Si	0.2591	0.7500	0.000				
Μσ	0.2391	0.7500	0.528				
Mα	0.0725	0.2500	1 665				
Si	0.7578	0.2500	1.005				
Ma	0.7578	0.2500	2 /02				
Mg	0.9765	0.7500	3 766				
Si	0.2578	0.2500	J.700 1 707				
Ma	0.2378	0.2500	4.292				
Mg	0.0440	0.2500	5 720				
si	0.3723	0.7500	5.730				
	0.7391	0.7500	6.083				
Ivig	$\frac{0.9694}{\text{Cubic Mg}Si(111)} d$	$-2.0 \text{ nm} \ a = 4.483 \text{ Å}$	0.239				
Ма	0.0000	-2.0 mm, $u_{\rm hex} - 4.403$ A	0.000				
s;	0.0000	0.0000	0.000				
	0.0007	0.5555	1.696				
Mg	0.5555	0.0007	1.000				
Nig Si	0.0007	0.5555	5.492 A A21				
	0.5555	0.0007	4.431				
Ma	0.0000	0.0000	J.JJU 7 199				
IVIg	0.5555	0.0007	/.100				
	0.0000	0.0000	8.100				
Mg	0.0007	0.3333	9.025				
Mg	0.0000	0.0000	10.801				
S1	0.0007	0.3333	11./80				
Mg	0.3333	0.6667	12.69/				
Mg	0.6667	0.3333	14.536				
	0.3333	0.6667	15.455				
Mg	0.0000	0.0000	16.393				
Mg	0.3333	0.6667	18.200				
S1	0.0000	0.0000	19.201				
Mg	0.6667	0.3333	19.886				
Cubic Ca ₂ Si(111), $d = 2.3$ nm, $a_{hex} = 4.999$ A							
Ca	0.0000	0.0000	0.000				
S1	0.6667	0.3333	1.014				
Ca	0.3333	0.6667	2.092				
Ca	0.6667	0.3333	4.169				
Si	0.3333	0.6667	5.223				
Ca	0.0000	0.0000	6.276				

Table T1. Structural information on atomic positions and lattice parameters of Me_2Si thin films shown in Figs. 1 and 2

Ca	0.3333	0.6667	8.350
Si	0.0000	0.0000	9.401
Ca	0.6667	0.3333	10.455
Ca	0.0000	0.0000	12.531
Si	0.6667	0.3333	13.585
Са	0.3333	0.6667	14.636
Ca	0.6667	0.3333	16.710
Si	0 3333	0.6667	17 763
Ca	0.0000	0.0007	18 817
Ca	0.3333	0.6667	20.894
Ca Si	0.0000	0.0007	20.074
	0.0000	0.3333	21.972
Orthor	$\frac{0.0007}{\text{hombic Ca Si(100)} d = 2.2}$	$\frac{0.3333}{nm \ a \ c} = 4.810 \ \text{Å} \ b \ c$	<u> </u>
Ca	1000000000000000000000000000000000000	$\frac{1}{10000000000000000000000000000000000$	$_{1} = 0.007 \text{ A}$
Ca	0.2500	0.8095	0.000
Ca C'	0.2500	0.4039	0.427
S1	0.7500	0.6153	1.089
S1	0.2500	0.1054	1.596
Ca	0.7500	0.9386	2.192
Ca	0.7500	0.3256	3.057
Ca	0.2500	0.6797	3.495
Ca	0.2500	0.0761	4.553
Si	0.7500	0.8894	5.233
Si	0.2500	0.3991	5.257
Ca	0.7500	0.5698	6.012
Ca	0.7500	0.1714	7.024
Ca	0.2500	0.8142	7.308
Ca	0.2500	0.4189	8.335
Si	0.7500	0.5958	9.053
Si	0.2500	0.0974	9.113
Ca	0.7500	0.9169	9.811
Ca	0.7500	0.3141	10.836
Ca	0.2500	0.6702	11.152
Ca	0.2500	0.0674	12.176
Si	0.7500	0.8869	12.874
Si	0.2500	0.3885	12.934
Ca	0.7500	0.5653	13 653
Ca	0.7500	0.1701	14 679
Ca	0.2500	0.8129	14 964
Ca	0.2500	0.4145	15 976
Si	0.2500	0.5852	16 731
Si	0.7500	0.0040	16 754
	0.2500	0.0047	10.754
Ca	0.7500	0.2016	17.754
Ca	0.7500	0.3040	10. 4 72 10.921
Ca	0.2300	0.030/	10.701
Ca C'	0.2500	0.045/	19.795
S1	0./500	0.8/88	20.391
S1	0.2500	0.3690	20.899
Ca	0.7500	0.5804	21.561
Ca	0.7500	0.1748	21.987

Ca	0.3845	0.1324	0.000
Ca	0.1155	0.6324	0.000
Si	0.0827	0.2525	0.473
Si	0.4173	0.7525	0.473
Ca	0.8152	0.0297	0.706
Ca	0.6848	0.5297	0.706
Si	0.6002	0.2441	2.655
Si	0.8998	0.7441	2.655
Ca	0.3249	0.4795	2.681
Ca	0.1751	0.9795	2.681
Ca	0.9295	0 3528	2.869
Ca	0.5705	0.8528	2.869
Ca	0.4226	0.1565	5 173
Ca	0.0774	0.6565	5 173
Ca	0.8243	0.0210	5 225
Ca	0.6757	0.5210	5 225
Si	0.1042	0.2554	5 261
Si	0.3058	0.2554	5 261
Si	0.5758	0.7554	7 588
Si	0.8066	0.2403	7.588
	0.3210	0.7403	7.500
Ca Ca	0.1790	0.4022	7.614
Ca Ca	0.9250	0.3490	7.634
Ca Ca	0.5750	0.3490	7.634
Ca	0.3750	0.1568	10.028
Ca	0.4250	0.1508	10.028
Ca	0.8210	0.0208	10.020
Ca	0.6790	0.0230	10.049
Ca Si	0.103/	0.3230	10.07/
Si	0.1054	0.2575	10.074
Si	0.5700	0.7575	12 402
Si	0.8058	0.2504	12.402
	0.3243	0.7504	12.402
Ca Ca	0.1757	0.9848	12.438
Ca Ca	0.9226	0.2493	12.490
Ca Ca	0.5774	0.8493	12.490
Ca Ca	0.4295	0.1530	12.490
Ca Ca	0.4295	0.6530	14.794
Ca Ca	0.8749	0.0350	14 981
Ca Ca	0.6751	0.5264	14 981
Si	0.1002	0.2617	15 007
Si	0.3998	0.2017	15.007
Ca	0.3152	0.4761	16.956
Ca Ca	0.1848	0.9761	16.956
Si	0.5827	0.2533	17 190
Si	0.9173	0.7533	17 100
	0.9175	0.733	17.663
Ca Ca	0.0045	0.5734	17.003
Ca Orthorbo	$\frac{0.0133}{\text{mbic CasSi(001)} \ d = 2.1}$	$nm \ a = 7.505 \ \text{\AA} \ h$	= 4.837 Å
Ca	Ω 7731	ο 5 000	A חחח ח
Ca	0.//51	-	0.000
		5	

Si	0.9817	0.0000	0.643
Са	0.3741	0.0000	0.652
Са	0.0958	0.5000	2.167
Si	0.4928	0.5000	2.268
Са	0.7525	0.0000	3.027
Са	0.2519	0.0000	4.366
Si	0.9878	0.5000	5.049
Са	0.5837	0.5000	5.240
Са	0.8921	0.0000	6.633
Si	0.4910	0.0000	6.866
Са	0.2203	0.5000	7.560
Са	0.7208	0.5000	8.839
Si	0.9915	0.0000	9.528
Ca	0.3940	0.0000	9.771
Ca	0.0841	0.5000	11.133
Si	0.4866	0.5000	11.376
Ca	0.7573	0.0000	12.064
Ca	0.2578	0.0000	13.343
Si	0.9871	0.5000	14.037
Ca	0.5860	0.5000	14.270
Ca	0.8944	0.0000	15.663
Si	0.4903	0.0000	15.855
Ca	0.2262	0.5000	16.538
Ca	0.7256	0.5000	17.876
Si	0.9854	0.0000	18.635
Ca	0.3824	0.0000	18.736
Ca	0.1040	0.5000	20.252
Si	0.4964	0.5000	20.260
Са	0.7050	0.0000	20.903



Fig. S3 The corresponding Brillouin zones and band structures of Me₂Si bulks represented by face-centered cubic and hexagonal symmetries. For the sake of comparison the face-centered cubic Brillouin zone (top left) is merged with its equivalent hexagonal representation. The high symmetry points of the Brillouin zones labelled in black and in red correspond to face-centered cubic and hexagonal symmetries, respectively.